



1200V SiC Schottky Diode

VDC	1200 V
Q _c	269 nC
I _F	50 A
T _j ,max	175 °C

Amp+[™] Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 666mJ*
- All parts tested to greater than 1,400V

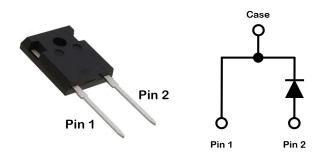
Amp+[™] Benefits

- Near zero switching loss
- Higher efficiency
- · Smaller heat sink
- Easy to parallel

Amp+[™] Applications

- Solar Inverters
- · Switch mode power supplies, UPS
- Power factor correction
- · EV charging stations

Package



Part #	Package	Marking
GP3D050A120B	TO-247-2L	3D050A120



Maximum Ratings, at T_i=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values	Unit	
Continuous forward current	I _{F**}	T _C =25 °C, T _j =175 °C	136		
		T _C =125 °C, T _j =175 °C	74	A	
		T _C =150 °C, T _j =175 °C	48		
Surge non-repetitive forward current		T _C =25 °C, t _p =8.3 ms	390	^	
sine halfwave	I _{FSM}	T _C =110 °C, t _p =8.3 ms	340	A	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	2000***	А	
i²t value	∫i²dt	T _C =25 °C, t _p =8.3 ms	631	.2	
		T _C =110 °C, t _p =8.3 ms	480	$ A^2$ s	
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	1200	V	
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns	
Power dissipation	P _{tot**}	T _C =25 °C	600	W	
Operating junction & storage temperature	$T_{j},T_{storage}$	Continuous	-55175	°C	
Soldering temperature	T _{solder}	Wave soldering leads	260	°C	
Mounting torque		M3 Screw	1	N-m	

Notes:

^{*} EAS of 666 mJ is based on starting Tj = 25° C, L = 1.0 mH, IAS = 36.50 A, V = 50 V.

^{**} Typical Rth_{JC} used

^{***} Limited by testing equipment

$Amp + ^{TM}$

Electrical Characteristics, at T_j=25 °C, unless otherwise specified

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Unit
DC blocking voltage	V _{DC}	T _j =25 °C	1200	-	-	V
Breakdown voltage	V _{BR}	I _R =2.00mA, T _j =25 °C	1400	-	-	V
Diode forward voltage		I _F =50A, T _j =25 °C	-	1.50	1.70	V
	V _F	I _F =50A, T _j =125 °C	-	1.82	-	
		I _F =50A, T _j =175 °C	-	2.10	2.70	
Reverse current	I _R	V _R =1,200V, T _j =25 °C	-	6	100	μΑ
		V _R =1,400V, T _j =25 °C	-	35	-	
		V _R =1,200V, T _j =125 °C	-	49	-	
		V _R =1,200V, T _j =175 °C	-	193	750	
Total capacitive charge	Q _C	V _R =800V, T _j =25 °C	-	269	-	nC
Total capacitance	С	V _R =1V, f=1 MHz	-	3040	-	pF
		V _R =400V, f=1 MHz	-	253	-	
		V _R =800V, f=1 MHz	-	181	-	

Thermal Characteristics

Characteristics	Symbol	Conditions	Values			Unit
			min.	typ.	max.	Ollit
Thermal resistance, junction-case	R _{thJC}	-	-	0.25	0.35	°C/W

Typical Performance

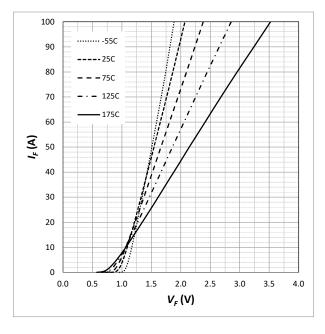


Fig. 1 Forward Characteristics (parameterized on T_i)

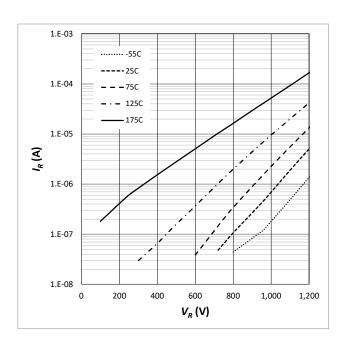
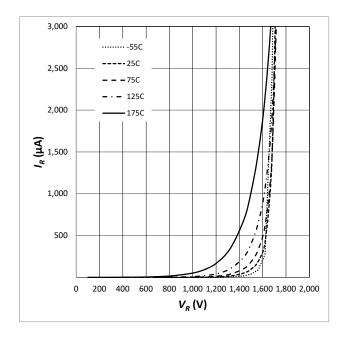


Fig. 2 Reverse Characteristics (parameterized on T_i)



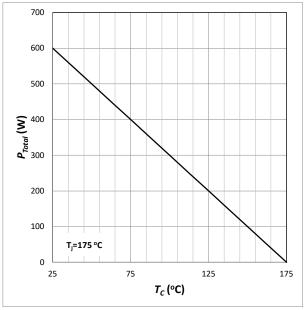
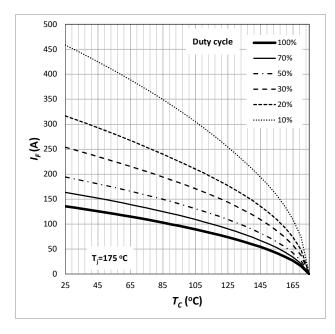


Fig. 3 Reverse Characteristics (parameterized on Tj)

Fig. 4 Power Derating





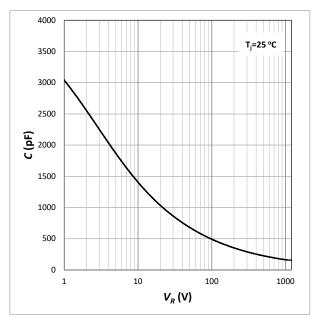
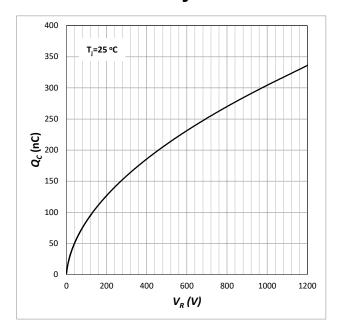


Fig. 6 Capacitance



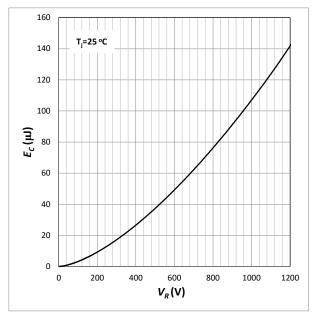


Fig. 7 Capacitive Charge

Fig. 8 Typical Capacitance Stored Energy

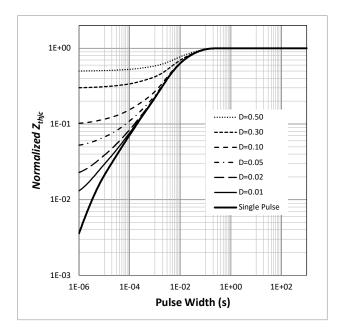
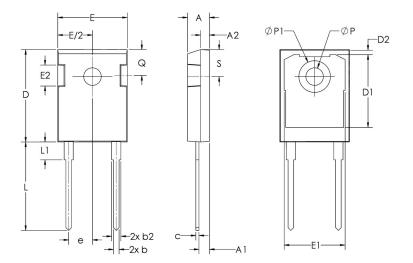


Fig. 9 Transient Thermal Impedance

Package Dimensions TO-247-2L



Sym	Millimeters		Inches		
Sylli	Min	Max	Min	Max	
Α	4.70	5.31	0.185	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b2	1.65	2.39	0.065	0.094	
С	0.38	0.89	0.015	0.035	
D	20.80	21.46	0.819	0.845	
D1	13.08	17.65	0.515	0.695	
D2	0.51	1.35	0.020	0.053	
E	15.49	16.26	0.610	0.640	
E1	13.46	14.16	0.530	0.557	
E2	3.43	5.49	0.135	0.216	
е	5.44 BSC		.214 BSC		
L	19.81	20.32	0.780	0.800	
L1	4.10	4.50	0.161	0.177	
ØP	3.56	3.66	0.140	0.144	
ØP1	7.06	7.39	0.278	0.291	
Q	5.38	6.20	0.212	0.244	
S	6.04	6.30	0.238	0.248	

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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